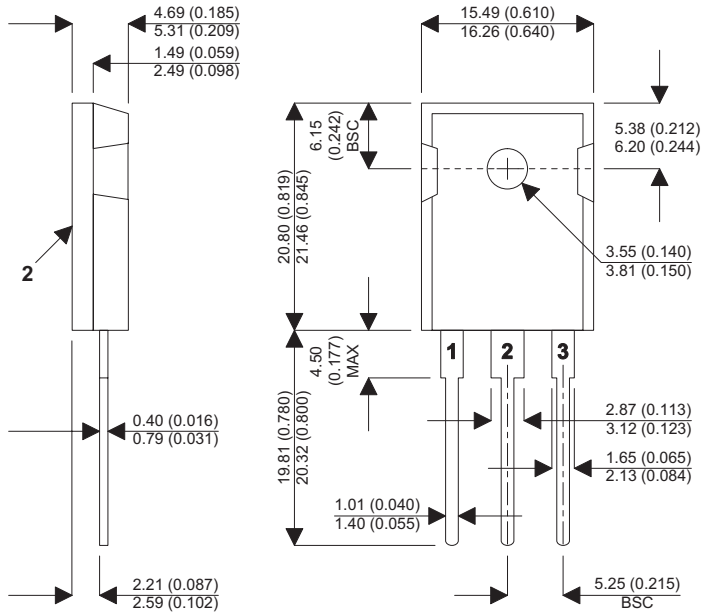


MECHANICAL DATA

Dimensions in mm (inches)



TO-247

PIN 1 – Base PIN 2 – Collector PIN 3 – Emitter.

NPN MULTI-EPITAXIAL POWER TRANSISTOR

FEATURES

- LOW $V_{CE(sat)}$
- FAST SWITCHING
- HIGH CURRENT
- HIGH RELIABILITY

APPLICATIONS

- HIGH FREQUENCY AND EFFICIENCY CONVERTERS
- SWITCHING REGULATORS
- MOTOR CONTROLS

ABSOLUTE MAXIMUM RATINGS ($T_{case} = 25^{\circ}C$ unless otherwise stated)

V_{CEX}	Collector – Emitter Voltage ($V_{BE} = -1.5V$)	300V
V_{CEO}	Collector – Emitter Voltage ($I_B = 0$)	160V
V_{EBO}	Emitter – Base Voltage	7V
I_C	Collector Current	30A
$I_{C(PK)}$	Peak Collector Current	40A
I_B	Base Current	8A
$I_{B(pk)}$	Peak Base Current	15A
P_{tot}	Total Dissipation at $T_{case} = 25^{\circ}C$	175W
T_{STG}	Storage Temperature Range	-55 to 200°C
T_J	Maximum Operating Junction Temperature	200°C
R_{qJC}	Thermal Resistance (Junction – Case)	0.875°C/W Max.

Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

ELECTRICAL CHARACTERISTICS ($T_{\text{case}} = 25^{\circ}\text{C}$ unless otherwise stated)

Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$V_{\text{CEO(sus)}}$ Collector - Emitter Sustaining Voltage	$I_{\text{C}} = 0.2\text{A}$ $I_{\text{B}} = 0$ $L = 25\text{mH}$	160			V
$V_{(\text{BR})\text{EBO}}$ Emitter – Base Breakdown Voltage	$I_{\text{C}} = 0$ $I_{\text{E}} = 1\text{mA}$	7			V
I_{CEX} Collector Cut-off Current	$V_{\text{CE}} = V_{\text{CEX}}$ $V_{\text{BE}} = -1.5\text{V}$ $T_{\text{J}} = 100^{\circ}\text{C}$			1.0 4.0	mA
I_{CER} Collector Cut-off Current	$R_{\text{BE}} = 10\Omega$ $V_{\text{CE}} = V_{\text{CEX}}$ $T_{\text{J}} = 100^{\circ}\text{C}$			1.0 5.0	
I_{EBO} Emitter Cut-off Current	$I_{\text{C}} = 0$ $V_{\text{BE}} = -5\text{V}$			0.5	mA
$V_{\text{CE(sat)*}}$ Collector – Emitter Saturation Voltage	$I_{\text{C}} = 25\text{A}$ $I_{\text{B}} = 2.5\text{A}$ $T_{\text{J}} = 100^{\circ}\text{C}$		0.5	0.9 1.5	V
$V_{\text{BE(sat)*}}$ Base – Emitter Saturation Voltage	$I_{\text{C}} = 25\text{A}$ $I_{\text{B}} = 2.5\text{A}$ $T_{\text{J}} = 100^{\circ}\text{C}$		1.2	1.5 1.4	

* Pulse Test: $t_{\text{p}} = 300\mu\text{s}$, $\delta \leq 2\%$

SWITCHING CHARACTERISTICS ($T_{\text{case}} = 25^{\circ}\text{C}$ unless otherwise stated)

Parameter	Test Conditions	Min.	Typ.	Max.	Unit
Switching Characteristics (Resistive Load)					
t_{r} Rise Time	$I_{\text{C}} = 20\text{A}$			0.8	μs
t_{s} Storage Time	$I_{\text{B1}} = I_{\text{B2}} = 2.5\text{A}$			2.2	
t_{f} Fall Time	$V_{\text{CC}} = 80\text{V}$			0.6	

Preliminary Datasheet